## Excitonic transitions in 2D transition metal dichalcogenides (MoS<sub>2</sub>, WS<sub>2</sub> and WSe<sub>2</sub>) observed by resonance Raman spectroscopy

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## Abstract

Resonance Raman spectroscopy (RRS) is a very useful tool to provide information about excitons and their couplings with phonons. We will present in this work a RRS study of different samples of 2D transition metal dichalcogenides (MoS<sub>2</sub>, WS<sub>2</sub> and WSe<sub>2</sub>) with one, two and three layers (1L, 2L, 3L) and bulk samples, using more than 30 different laser excitation lines covering the visible range. We have observed that all Raman features are enhanced by resonanceswith excitonic transitions. From the laser energy dependence of the Raman excitation profile (REP) we obtained the energies of the excitonic states and their dependence with the number of atomic layers. The first and second-order Raman features exhibit different resonance behaviors, in agreement with the double resonance mechanism for the second-order Raman features. In the case of MoS<sub>2</sub>, we observed that the electronphonon coupling is symmetry dependent, and we provide evidence of the C exciton recently predicted theoretically. The RRS results WSe<sub>2</sub> show that the Raman modes are enhanced by the excited excitonic states (A' and B') and we will present the dependence of the excited states energies on the number of layers.